

**Product data sheet** 

## 1. Product profile

#### 1.1 General description

PNP transistor in a SOT416 (SC-75) plastic package. The NPN complement is 2PC4617.

#### 1.2 Features

- Low current (max. 150 mA)
- Low voltage (max. 50 V)

### 1.3 Applications

 General-purpose switching and amplification in communication, Electronic Data Processing (EDP) and consumer applications.

## 2. Pinning information

Table 1. Pinning

Pin Description Simplified outline Symbol

1 base
2 emitter
3 collector

## 3. Ordering information

Table 2. Ordering information

Type number	Package				
	Name	Description	Version		
2PA1774Q	SC-75	plastic surface mounted package; 3 leads	SOT416		
2PA1774R					
2PA1774S					



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## **Marking**

**Marking codes** Table 3.

Type number	Marking code
2PA1774Q	YQ
2PA1774R	YR
2PA1774S	YS

## **Limiting values**

Table 4. **Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{CBO}}$	collector-base voltage	open emitter	-	-60	V
$V_{CEO}$	collector-emitter voltage	open base	-	-50	V
$V_{EBO}$	emitter-base voltage	open collector	-	-6	V
I <sub>C</sub>	collector current (DC)		-	-150	mA
$I_{CM}$	peak collector current		-	-200	mA
I <sub>BM</sub>	peak base current		-	-100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$	[1] -	150	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-65	+150	°C

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

## Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		<u>[1]</u> -	-	833	K/W

<sup>[1]</sup> Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

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#### **Characteristics** 7.

Table 6. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V}$		-	-	-100	nA
		$I_E = 0 \text{ A}; V_{CB} = -30 \text{ V};$ $T_j = 150 \text{ °C}$		-	-	<b>-5</b>	μА
I <sub>EBO</sub>	emitter-base cut-off current	$I_C = 0 A; V_{EB} = -4 V$		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$I_C = -1 \text{ mA}; V_{CE} = -6 \text{ V}$	[1]				
	2PA1774Q			120	-	270	
	2PA1774R			180	-	390	
	2PA1774S			270	-	560	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -50 \text{ mA};$ $I_B = -5 \text{ mA}$	[1]	-	-	-200	mV
C <sub>c</sub>	collector capacitance	$I_E = I_e = 0 \text{ A};$ $V_{CB} = -12 \text{ V}; f = 1 \text{ MHz}$		-	-	2.2	pF
f <sub>T</sub>	transition frequency	$I_E = -2 \text{ mA};$ $V_{CE} = -12 \text{ V};$ f = 100  MHz	<u>[1]</u>	100	-	-	MHz

<sup>[1]</sup> Pulse test:  $t_p \le 300~\mu s;~\delta \le 0.02.$ 

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## 8. Package outline

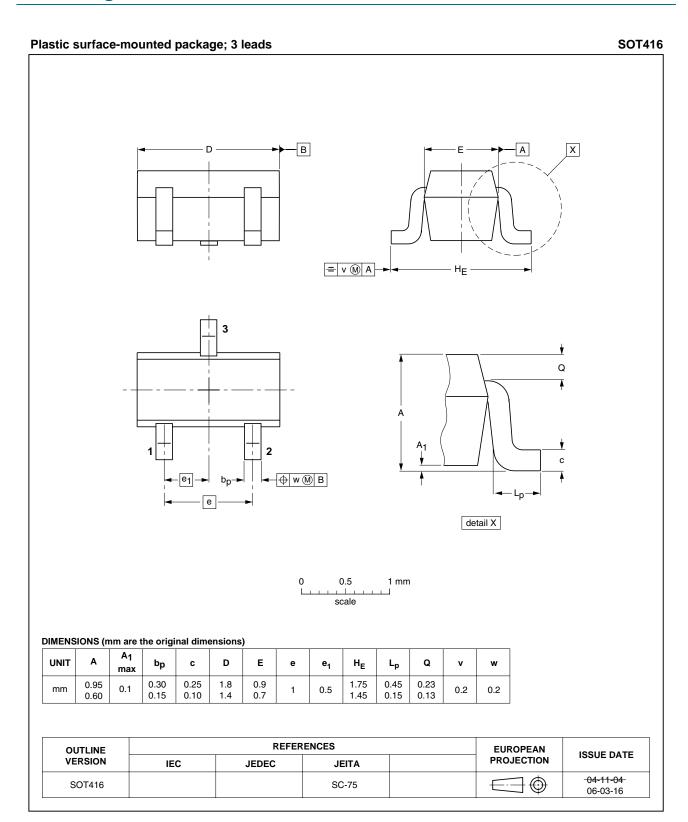


Fig 1. Package outline SOT416 (SC-75)

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# 9. Revision history

### Table 7. Revision history

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Document ID	Release date	Data sheet status	Change notice	Supersedes
2PA1774_5	20091117	Product data sheet	-	2PA1774_4
Modifications:	including ned content.	eet was changed to reflect w legal definitions and discleckage outline SOT416 (SC	aimers. No changes w	
2PA1774_4	20041124	Product data sheet	-	2PA1774_3
2PA1774_3	20001212	Product specification	-	2PA1774_2
2PA1774_2	19990601	Preliminary specification	on -	2PA1774_1
2PA1774_1	19970709	Preliminary specification	on -	-

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## 10. Legal information

#### Data sheet status 10.1

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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